

- **Wide Operating Voltage Range: 2V to 16V**
- **Low Current Consumption: 2.7 mA Typically**
- **Chip Disable Input to Power Down the Integrated Circuit**
- **Low Power-down Quiescent Current**
- **Drives a Wide Range of Speaker Loads**
- **Output Power $P_o = 250 \text{ mW}$ at $R_L = 32\Omega$ (Speaker)**
- **Low Harmonic Distortion (0.5% Typically)**
- **Wide Gain Range: 0 dB to 46 dB**

- **Low Number of External Components**
- **Low Current Consumption**

The integrated circuit U4083B is a low-power audio amplifier for telephone loudspeakers. It has differential speaker outputs to maximize the output swing at low supply voltages. There is no need for coupler capacitors. The U4083B has an open-loop gain of 80 dB where the closed-loop gain is adjusted with two external resistors. A chip disable pin permits powering down and/or muting the input signal.

The diagram shows a two-stage op-amp circuit using a U4083B dual op-amp. The circuit includes a bias circuit, two op-amp stages (Amp1 and Amp2), and various resistors and a diode. Inputs are labeled V_i , FC3, and FC2. Outputs are labeled VO1 and VO2. Power supply pins are labeled VS, CD, and GND.

- U4083B:** A dual op-amp with two stages, Amp1 and Amp2.
- Bias circuit:** A block connected to pin 1 (CD) and pin 7 (GND).
- Inputs:**
 - V_i (pin 4) is connected to the non-inverting input of Amp1.
 - FC3 (pin 3) is connected to the inverting input of Amp1.
 - FC2 (pin 2) is connected to the non-inverting input of Amp2.
- Outputs:**
 - VO1 (pin 5) is the output of Amp1.
 - VO2 (pin 8) is the output of Amp2.
- Resistors:**
 - 50k resistor between pin 3 and pin 2.
 - 125k resistor between pin 2 and the non-inverting input of Amp2.
 - 4k resistor between the output of Amp1 and the inverting input of Amp2.
 - 4k resistor between the output of Amp1 and the non-inverting input of Amp2.
- Diode:** A diode is connected between pin 3 and pin 2, with its cathode towards pin 3.



Low-power Audio Amplifier for Telephone Applications

U4083B

Rev. 4655C-CORD-03/06

2. Pin Configuration

Figure 2-1. Pinning SO8

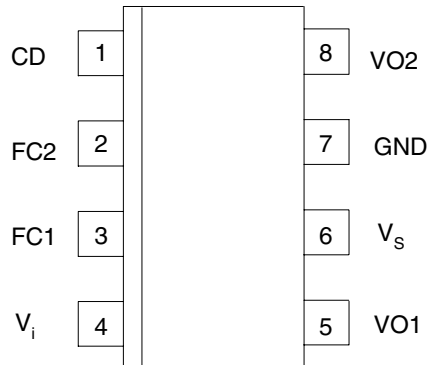


Table 2-1. Pin Description

Pin	Symbol	Function
1	CD	Chip disable
2	FC2	Filtering, power supply rejection
3	FC1	Filtering, power supply rejection
4	V_i	Amplifier input
5	VO1	Amplifier output 1
6	V_s	Voltage supply
7	GND	Ground
8	VO2	Amplifier output 2

3. Functional Description Including External Circuitry

3.1 Pin 1: Chip Disable Digital Input (CD)

Pin 1 (chip disable) is used to power down the IC to conserve power or mute the IC or both.

Input impedance at Pin 1 is typically 90 k Ω

- Logic 0 < 0.8V IC enabled (normal operation)
- Logic 1 > 2V IC disabled

Figure 8-15 on page 12 shows the power supply current diagram. The change in differential gain from normal operation to muted operation (muting) is more than 70 dB.

Switching characteristics are as follows:

- Turn-on time $t_{on} = 12 \text{ ms to } 15 \text{ ms}$
- Turn-off time $t_{off} \leq 2 \mu\text{s}$

They are independent of C_1 , C_2 and V_S .

Voltages at Pins 2 and 3 are supplied from V_S and, therefore, do not change when the U4083B is disabled. The outputs, V_{O1} (Pin 5) and V_{O2} (Pin 8), turn to a high impedance condition by removing the signal from the speaker.

When signals are applied from an external source to the outputs (disabled), they must not exceed the range between the supply voltage, V_S , and ground.

3.2 Pins 2 and 3: Filtering, Power Supply Rejection

Power supply rejection is provided by capacitors C_1 and C_2 at Pin 3 and Pin 2, respectively. C_1 is dominant at high frequencies whereas C_2 is dominant at low frequencies (Figure 8-4 on page 8 to Figure 8-7 on page 9). The values of C_1 and C_2 depend on the conditions of each application. For example, a line-powered speakerphone (telephone amplifier) will require more filtering than a system powered by regulated power supply.

The amount of rejection is a function of the capacitors and the equivalent impedance at Pin 3 and Pin 2 (see electrical characteristic equivalent resistance, R).

Apart from filtering, capacitors C_1 and C_2 also influence the turn-on time of the circuit at power up, since the capacitors are charged up through the internal resistors (50 k Ω and 125 k Ω) as shown in the block diagram.

Figure 8-1 on page 7 shows the turn-on time versus C_2 at $V_S = 6\text{V}$, for two different C_1 values.

The turn-on time is 60% longer when $V_S = 3\text{V}$ and 20% shorter when $V_S = 9\text{V}$.

The turn-off time is less than 10 μs .

3.3 Pin 4: Amplifier Input V_i , Pin 5: Amplifier Output 1 V_{O1} , Pin 8: Amplifier Output 2 V_{O2}

There are two identical operational amplifiers. Amplifier 1 has an open-loop gain ≥ 80 dB at 100Hz (Figure 8-2 on page 7), whereas the closed-loop gain is set by external resistors, R_f and R_i (Figure 8-3 on page 8). The amplifier is unity gain stable, and has a unity gain frequency of approximately 1.5 MHz. A closed-loop gain of 46 dB is recommended for a frequency range of 300Hz to 3400Hz (voice band). Amplifier 2 is internally set to a gain of -1.0 dB (0 dB). The outputs of both amplifiers are capable of sourcing and sinking a peak current of 200 mA. Output voltage swing is between 0.4V and $V_S - 1.3V$ at maximum current (Figure 8-18 on page 13 and Figure 8-19 on page 13).

The output DC offset voltage between Pins 5 and 8 ($V_{O1} - V_{O2}$) is mainly a function of the feedback resistor, R_f , because the input offset voltages of the two amplifiers neutralize each other.

Bias current of Amplifier 1 which is constant with respect to V_S , flows out of Pin 4 (V_i) and through R_f , forcing V_{O1} to shift negative by an amount equal to $R_f I_{IB}$ and V_{O2} positive to an equal amount.

The output offset voltage specified in the electrical characteristics is measured with the feedback resistor ($R_f = 75$ k Ω) shown in the typical application circuit, Figure 8-20 on page 14. It takes into account the bias current as well as internal offset voltages of the amplifiers.

3.4 Pin 6: Supply and Power Dissipation

Power dissipation is shown in Figure 8-8 on page 9 to Figure 8-10 on page 10 for different loads. Distortion characteristics are given in Figure 8-11 on page 10 to Figure 8-13 on page 11.

$$P_{\text{totmax}} = \frac{T_{j\text{max}} - T_{\text{amb}}}{R_{\text{thJA}}}$$

where

$T_{j\text{max}}$ = Junction temperature = 140°C

T_{amb} = Ambient temperature

R_{thJA} = Thermal resistance, junction-ambient

Power dissipated within the IC in a given application is found from the following equation:

$$P_{\text{tot}} = (V_S \times I_S) + (I_{\text{RMS}} \times V_S) - (R_L \times I_{\text{RMS}}^2)$$

I_S is obtained from Figure 8-15 on page 12.

I_{RMS} is the RMS current at the load R_L .

The IC's operating range is defined by a peak operating load current of ± 200 mA (Figure 8-8 on page 9 to Figure 8-13 on page 11). It is further specified with respect to different loads (see Figure 8-14 on page 12). The left (ascending) portion of each of the three curves is defined by the power level at which 10% distortion occurs. The center flat portion of each curve is defined by the maximum output current capability of the integrated circuit. The right (descending) portion of each curve is defined by the maximum internal power dissipation of the IC at 25°C. At higher ambient temperatures, the maximum load power must be reduced according to the above mentioned equation.

3.5 Layout Considerations

Normally, a snubber is not needed at the output of the IC, unlike many other audio amplifiers. However, the PC-board layout, stray capacitances, and the manner in which the speaker wires are configured may dictate otherwise. Generally, the speaker wires should be twisted tightly, and should not be more than a few cm (or inches) in length.

4. Absolute Maximum Ratings

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Reference point pin 7, $T_{amb} = 25^{\circ}\text{C}$ unless otherwise specified.

Parameters	Symbol	Value	Unit
Supply voltage Pin 6	V_S	−1.0 to +18	V
Voltages Disabled Pins 1, 2, 3 and 4 Pins 5 and 8		−1.0 to ($V_S + 1.0$) −1.0 to ($V_S + 1.0$)	V V
Output current Pins 5 and 8		±250	mA
Junction temperature	T_j	+140	$^{\circ}\text{C}$
Storage temperature range	T_{stg}	−55 to +150	$^{\circ}\text{C}$
Ambient temperature range	T_{amb}	−20 to +70	$^{\circ}\text{C}$
Power dissipation SO8: $T_{amb} = 60^{\circ}\text{C}$	P_{tot}	440	mW

5. Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient SO8	R_{thJA}	180	K/W

6. Recommended Operating Conditions

Parameters	Symbol	Value	Unit
Supply voltage Pin 6	V_S	2 to 16	V
Load impedance Pins 5 to 8	R_L	8.0 to 100	Ω
Load current	I_L	±200	mA
Differential gain (5.0 kHz bandwidth)	DG	0 to 46	dB
Voltage at CD Pin 1	V_{CD}	V_S	V
Ambient temperature range	T_{amb}	−20 to +70	$^{\circ}\text{C}$

7. Electrical Characteristics

$T_{amb} = +25^{\circ}\text{C}$, reference point pin 7, unless otherwise specified

Parameters	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Amplifiers (AC Characteristics)						
Open-loop gain (Amplifier 1, $f < 100\text{Hz}$)		G_{VOL1}	80			dB
Closed-loop gain (Amplifier 2)	$V_S = 6.0\text{V}$, $f = 1.0\text{ kHz}$, $R_L = 32\Omega$	G_{V2}	-0.35	0	+0.35	dB
Gain bandwidth product		G_{BW}		1.5		MHz
Output power	$V_S = 3.0\text{V}$, $R_L = 16\Omega$, $d < 10\%$ $V_S = 6.0\text{V}$, $R_L = 32\Omega$, $d < 10\%$ $V_S = 12\text{V}$, $R_L = 100\Omega$, $d < 10\%$	P_O P_O P_O	55 250 400			mW
Total harmonic distortion ($f = 1.0\text{ kHz}$)	$V_S = 6.0\text{V}$, $R_L = 32\Omega$, $P_O = 125\text{ mW}$	d		0.5		%
	$V_S > 3.0\text{V}$, $R_L = 8\Omega$, $P_O = 20\text{ mW}$	d		0.5	1.0	
	$V_S > 12\text{V}$, $R_L = 32\Omega$, $P_O = 200\text{ mW}$	d		0.6		
Power supply rejection ratio	$V_S = 6.0\text{V}$, $\Delta V_S = 3.0\text{V}$ $C_1 = \alpha$, $C_2 = 0.01\text{ }\mu\text{F}$ $C_1 = 0.1\text{ }\mu\text{F}$, $C_2 = 0$, $f = 1.0\text{ kHz}$ $C_1 = 1.0\text{ }\mu\text{F}$, $C_2 = 5.0\text{ }\mu\text{F}$, $f = 1.0\text{ kHz}$	PSRR PSRR PSRR	50	12 52		dB
Muting	$V_S = 6.0\text{V}$, $1.0\text{ kHz} < f < 20\text{ kHz}$, $CD = 2.0\text{V}$	G_{MUTE}		>70		dB
Amplifiers (DC Characteristics)						
Output DC level at V_{O1} , V_{O2} $R_f = 75\text{ k}\Omega$	$V_S = 3.0\text{V}$, $R_L = 16\Omega$ $V_S = 6.0\text{V}$ $V_S = 12\text{V}$	V_O V_O V_O	1.0	1.15 2.65 5.65	1.25	V
Output high level	$I_O = -75\text{ mA}$, $2.0\text{V} < V_S < 16\text{V}$	V_{OH}		$V_S - 1$		V
Output low level	$I_O = -75\text{ mA}$, $2.0\text{V} < V_S < 16\text{V}$	V_{OL}		0.16		V
Output DC offset voltage ($V_{O1} - V_{O2}$)	$V_S = 6.0\text{V}$, $R_f = 75\text{ k}\Omega$, $R_L = 32\Omega$	ΔV_O	-30	0	+30	mV
Input bias current at V_i	$V_S = 6.0\text{V}$	$-I_{IB}$		100	200	nA
Equivalent resistance at Pin 3	$V_S = 6.0\text{V}$	R	100	150	220	k Ω
Equivalent resistance at Pin 2	$V_S = 6.0\text{V}$	R	18	25	40	k Ω
Chip disable Pin 1 Input voltage low Input voltage high Input resistance	$V_S = V_{CD} = 16\text{V}$	V_{IL} V_{IH} R_{CD}	2.0 50	90	0.8 175	V V k Ω
Power supply current	$V_S = 3.0\text{V}$, $R_L = \alpha$, $CD = 0.8\text{V}$ $V_S = 16\text{V}$, $R_L = \alpha$, $CD = 0.8\text{V}$ $V_S = 3.0\text{V}$, $R_L = \alpha$, $CD = 2.0\text{V}$	I_S I_S I_S		65	4.0 5.0 100	mA mA μA

8. Typical Temperature Performance

$T_{\text{amb}} = -20 \text{ to } +70^\circ\text{C}$

Function	Typical Change	Units
Input bias current at V_i	± 40	$\text{pA}/^\circ\text{C}$
Total harmonic distortion $V_S = 6.0\text{V}$, $R_L = 32\ \Omega$, $P_o = 125\text{ mW}$, $f = 1.0\text{ kHz}$	$+0.003$	$\%/^\circ\text{C}$
Power supply current $V_S = 3.0\text{V}$, $R_L = \alpha$, $CD = 0\text{V}$ $V_S = 3.0\text{V}$, $R_L = \alpha$, $CD = 2.0\text{V}$	-2.5 -0.03	$\mu\text{A}/^\circ\text{C}$ $\mu\text{A}/^\circ\text{C}$

Figure 8-1. Turn-on Time versus C_1 and C_2 at Power On

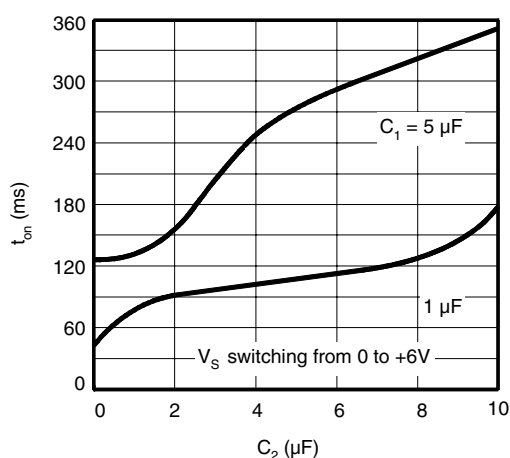


Figure 8-2. Amplifier 1 — Open-loop Gain and Phase

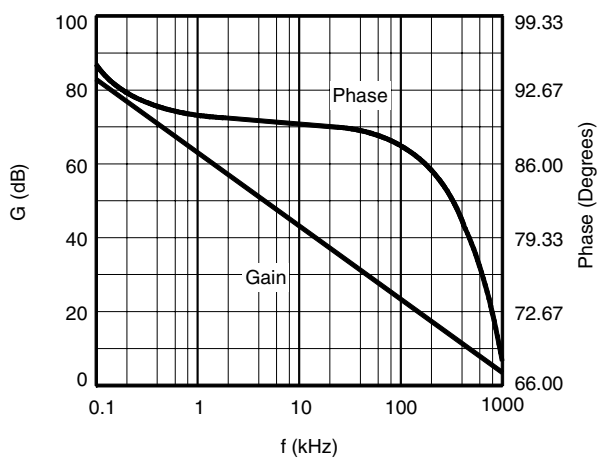


Figure 8-3. Differential Gain versus Frequency

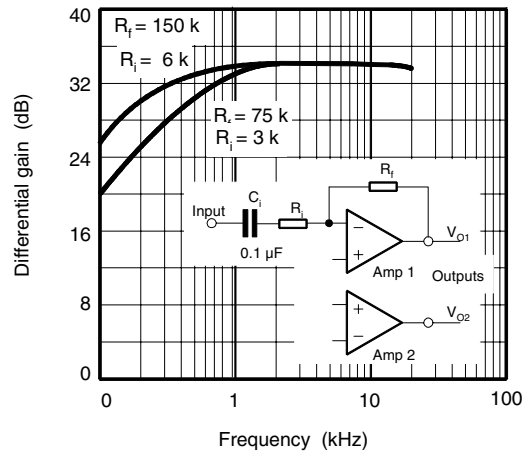


Figure 8-4. Power Supply Rejection versus Frequency — $C_2 = 10 \mu\text{F}$

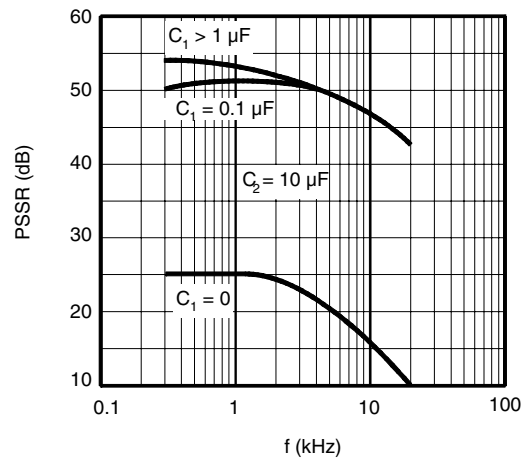


Figure 8-5. Power Supply Rejection versus Frequency — $C_2 = 5 \mu\text{F}$

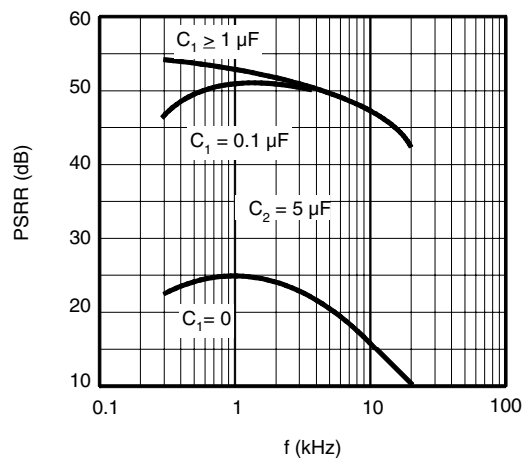


Figure 8-6. Power Supply Rejection versus Frequency — $C_2 = 1 \mu\text{F}$

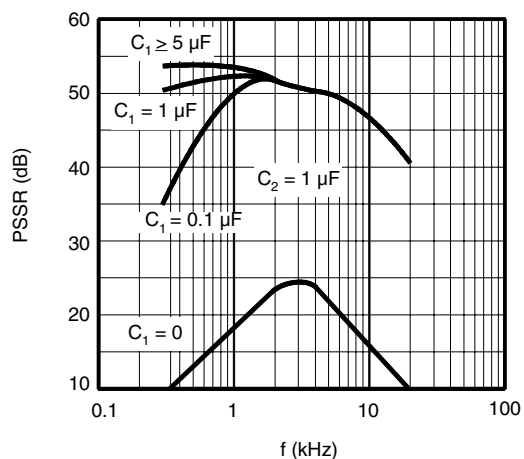


Figure 8-7. Power Supply Rejection versus Frequency — $C_2 = 0$

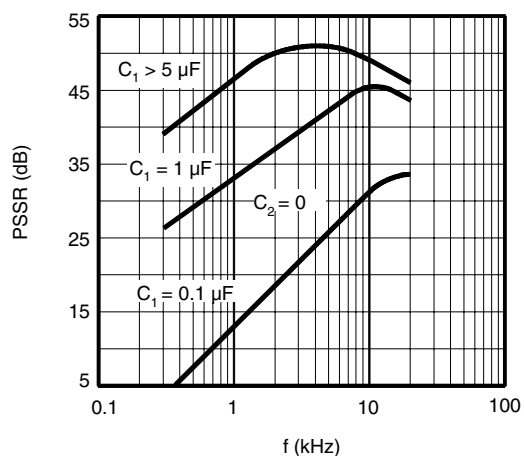


Figure 8-8. Device Dissipation — $R_L = 8 \Omega$

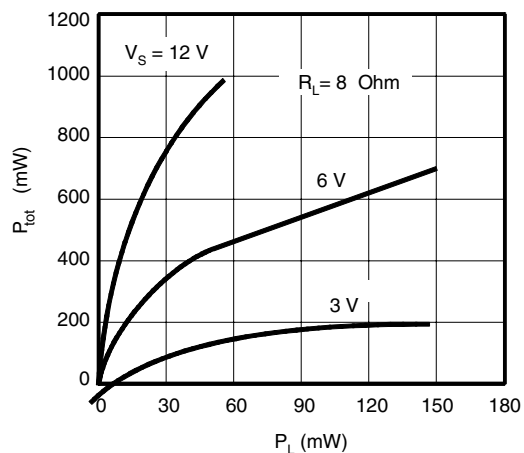


Figure 8-9. Device Dissipation — $R_L = 16\Omega$

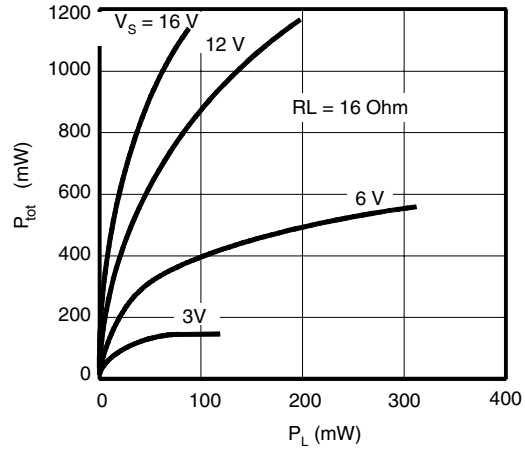


Figure 8-10. Device Dissipation — $R_L = 32\Omega$

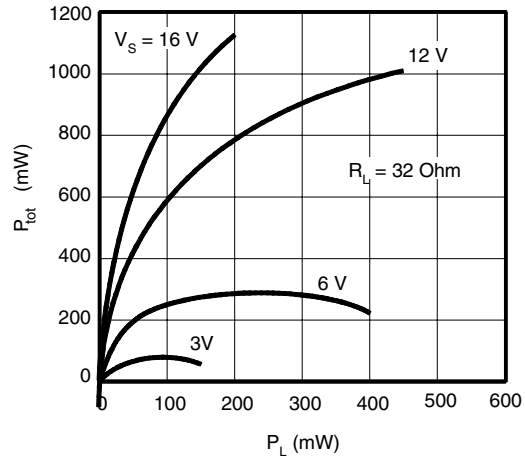


Figure 8-11. Distortion versus Power — $f = 1\text{ kHz}$, $\Delta - G_V = 34\text{ dB}$

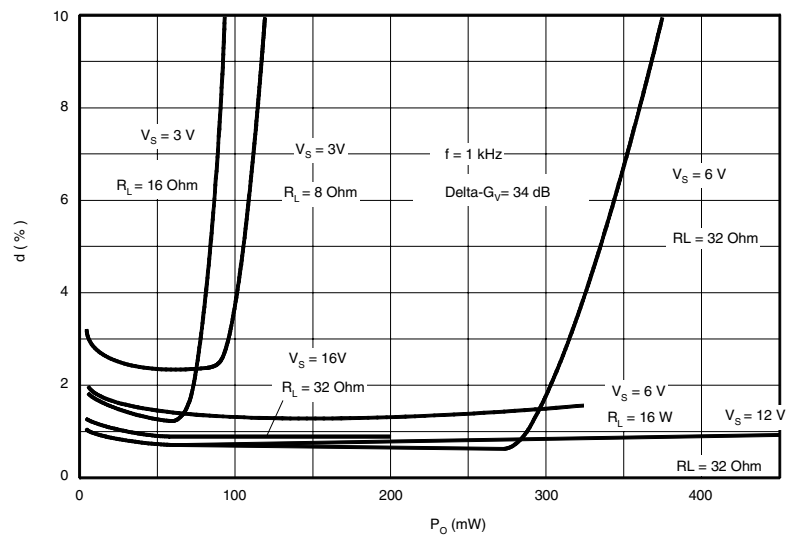


Figure 8-12. Distortion versus Power — $f = 3 \text{ kHz}$, $\Delta - G_V = 34 \text{ dB}$

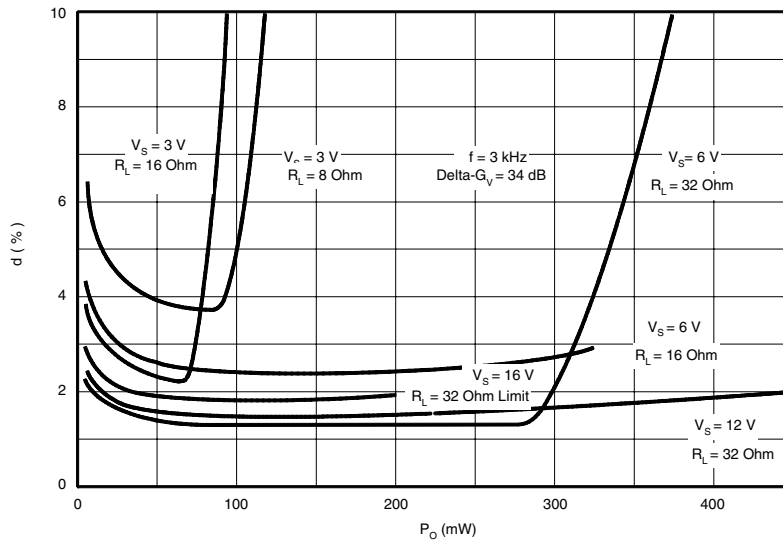


Figure 8-13. Distortion versus Power — $f = 1 \text{ kHz}$ or 3 kHz , $\Delta - G_V = 12 \text{ dB}$

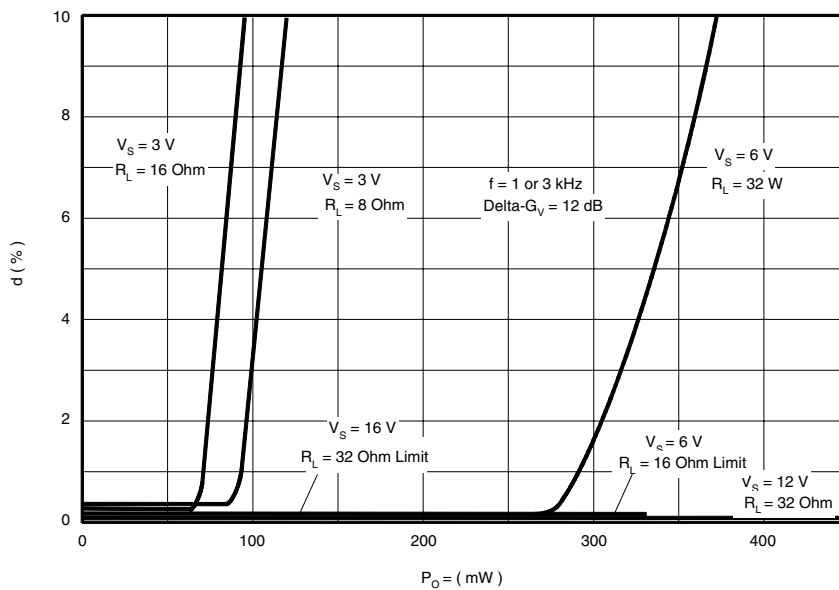


Figure 8-14. Maximum Allowable Load Power

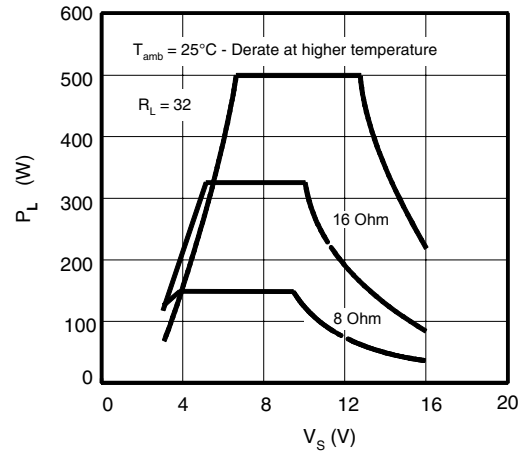


Figure 8-15. Power-supply Current

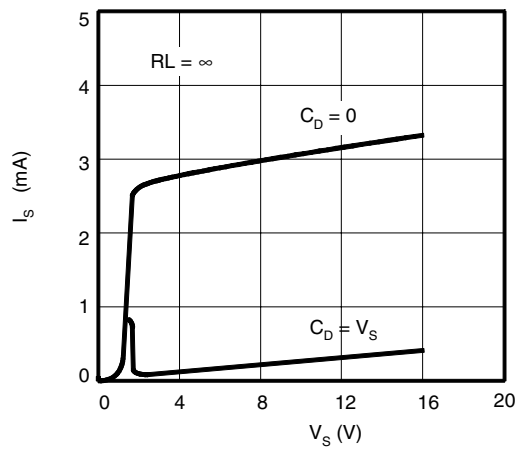


Figure 8-16. Small Signal Response

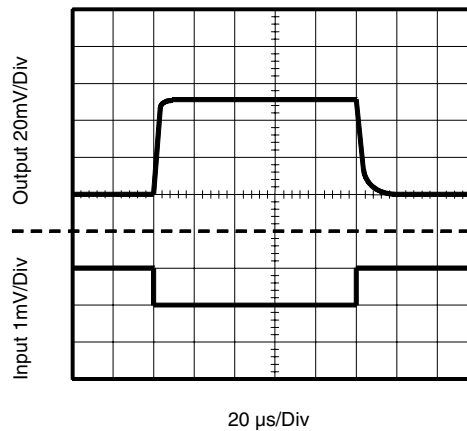


Figure 8-17. Large Signal Response

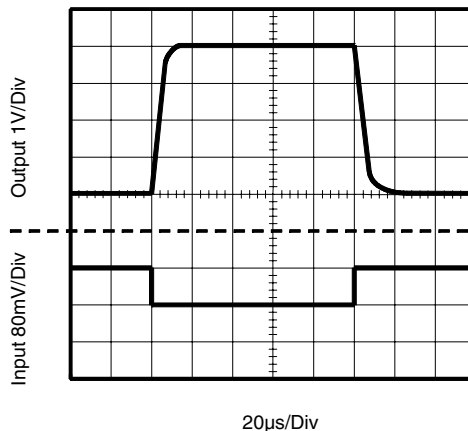


Figure 8-18. $V_S - V_{OH}$ versus Load Current

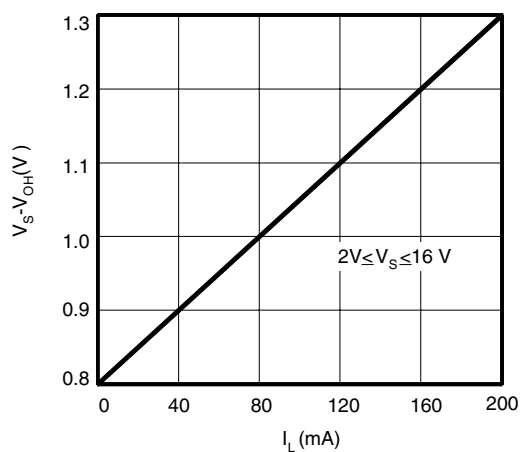


Figure 8-19. V_{OL} versus Load Current

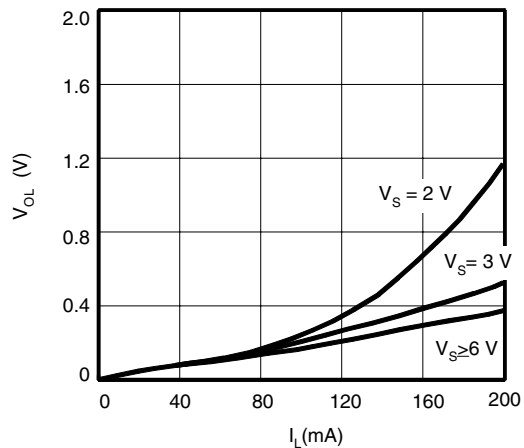
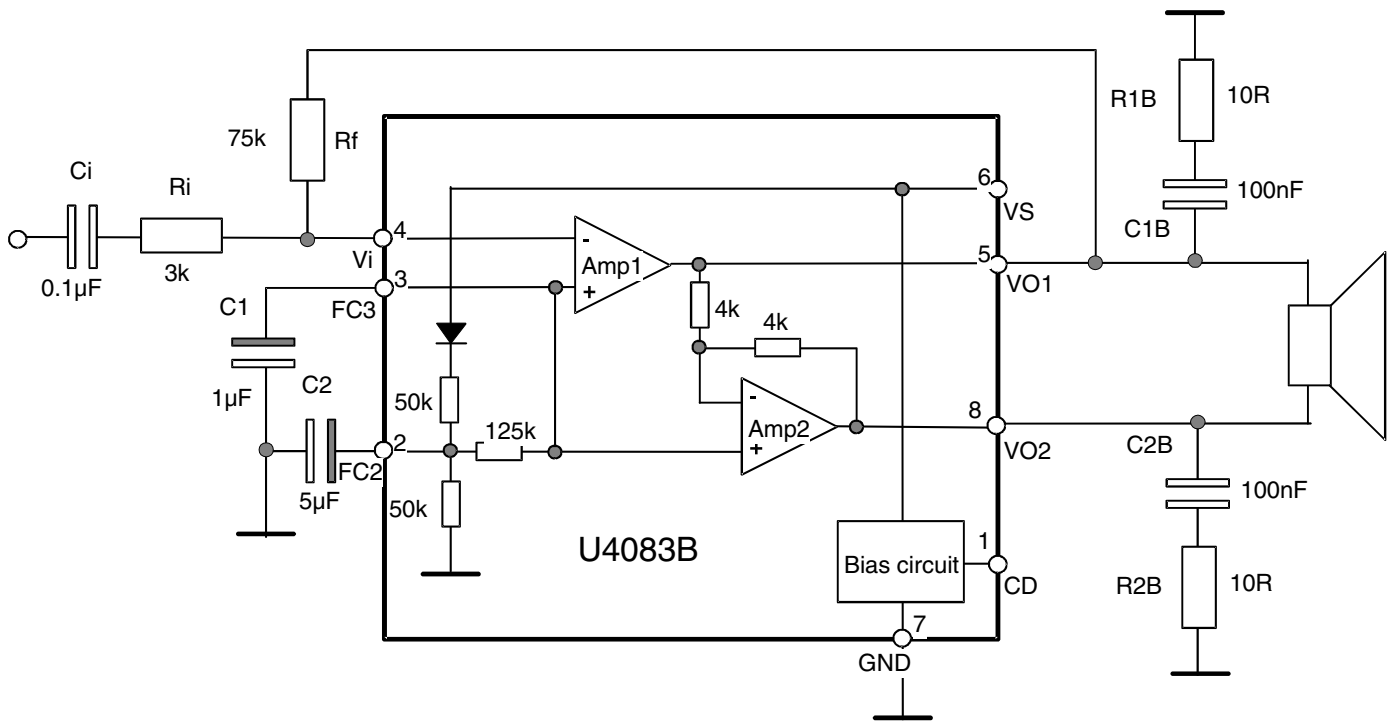


Figure 8-20. Application Circuit



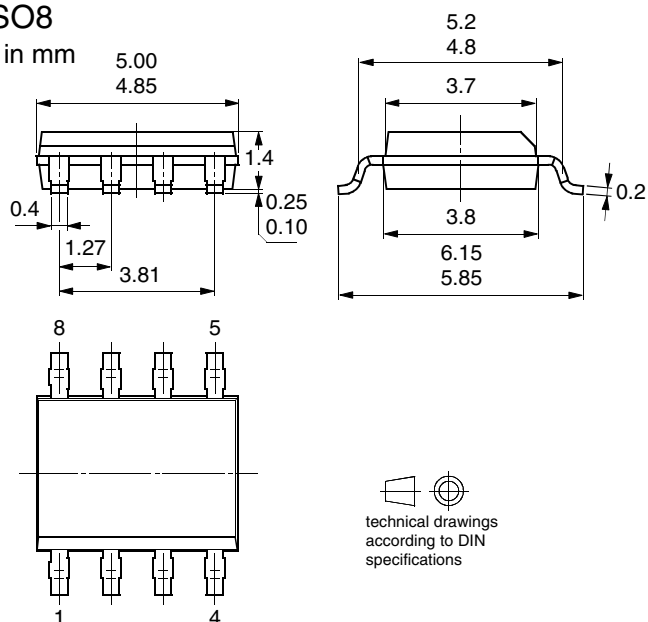
9. Ordering Information

Extended Type Number	Package	Remarks
U4083B-MFPY	SO8, Pb-free	Tube
U4083B-MFPG3Y	SO8, Pb-free	Taped and reeled

10. Package Information

Package SO8

Dimensions in mm





Atmel Corporation

2325 Orchard Parkway
San Jose, CA 95131, USA
Tel: 1(408) 441-0311
Fax: 1(408) 487-2600

Regional Headquarters

Europe

Atmel Sarl
Route des Arsenaux 41
Case Postale 80
CH-1705 Fribourg
Switzerland
Tel: (41) 26-426-5555
Fax: (41) 26-426-5500

Asia

Room 1219
Chinachem Golden Plaza
77 Mody Road Tsimshatsui
East Kowloon
Hong Kong
Tel: (852) 2721-9778
Fax: (852) 2722-1369

Japan

9F, Tonetsu Shinkawa Bldg.
1-24-8 Shinkawa
Chuo-ku, Tokyo 104-0033
Japan
Tel: (81) 3-3523-3551
Fax: (81) 3-3523-7581

Atmel Operations

Memory

2325 Orchard Parkway
San Jose, CA 95131, USA
Tel: 1(408) 441-0311
Fax: 1(408) 436-4314

Microcontrollers

2325 Orchard Parkway
San Jose, CA 95131, USA
Tel: 1(408) 441-0311
Fax: 1(408) 436-4314

La Chantrerie
BP 70602
44306 Nantes Cedex 3, France
Tel: (33) 2-40-18-18-18
Fax: (33) 2-40-18-19-60

ASIC/ASSP/Smart Cards

Zone Industrielle
13106 Rousset Cedex, France
Tel: (33) 4-42-53-60-00
Fax: (33) 4-42-53-60-01

1150 East Cheyenne Mtn. Blvd.
Colorado Springs, CO 80906, USA
Tel: 1(719) 576-3300
Fax: 1(719) 540-1759

Scottish Enterprise Technology Park
Maxwell Building
East Kilbride G75 0QR, Scotland
Tel: (44) 1355-803-000
Fax: (44) 1355-242-743

RF/Automotive

Theresienstrasse 2
Postfach 3535
74025 Heilbronn, Germany
Tel: (49) 71-31-67-0
Fax: (49) 71-31-67-2340

1150 East Cheyenne Mtn. Blvd.
Colorado Springs, CO 80906, USA
Tel: 1(719) 576-3300
Fax: 1(719) 540-1759

*Biometrics/Imaging/Hi-Rel MPU/
High Speed Converters/RF Datacom*
Avenue de Rochepleine
BP 123
38521 Saint-Egreve Cedex, France
Tel: (33) 4-76-58-30-00
Fax: (33) 4-76-58-34-80

Literature Requests

www.atmel.com/literature

Disclaimer: The information in this document is provided in connection with Atmel products. No license, express or implied, by estoppel or otherwise, to any intellectual property right is granted by this document or in connection with the sale of Atmel products. **EXCEPT AS SET FORTH IN ATMEL'S TERMS AND CONDITIONS OF SALE LOCATED ON ATMEL'S WEB SITE, ATMEL ASSUMES NO LIABILITY WHATSOEVER AND DISCLAIMS ANY EXPRESS, IMPLIED OR STATUTORY WARRANTY RELATING TO ITS PRODUCTS INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTY OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT. IN NO EVENT SHALL ATMEL BE LIABLE FOR ANY DIRECT, INDIRECT, CONSEQUENTIAL, PUNITIVE, SPECIAL OR INCIDENTAL DAMAGES (INCLUDING, WITHOUT LIMITATION, DAMAGES FOR LOSS OF PROFITS, BUSINESS INTERRUPTION, OR LOSS OF INFORMATION) ARISING OUT OF THE USE OR INABILITY TO USE THIS DOCUMENT, EVEN IF ATMEL HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES.** Atmel makes no representations or warranties with respect to the accuracy or completeness of the contents of this document and reserves the right to make changes to specifications and product descriptions at any time without notice. Atmel does not make any commitment to update the information contained herein. Unless specifically provided otherwise, Atmel products are not suitable for, and shall not be used in, automotive applications. Atmel's products are not intended, authorized, or warranted for use as components in applications intended to support or sustain life.

© Atmel Corporation 2006. All rights reserved. Atmel®, logo and combinations thereof, Everywhere You Are® and others, are registered trademarks or trademarks of Atmel Corporation or its subsidiaries. Other terms and product names may be trademarks of others.



Printed on recycled paper.